Structure of melt-quenched AgIn<sub>3</sub>Te<sub>5</sub>

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**Abstract** 

Polycrystalline AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench technique has been analyzed

using proton induced X-ray emission (PIXE), X-ray diffraction (XRD) and selected area

electron diffraction. PIXE analysis yielded the content of Ag, In and Te respectively to be

9.76%, 31.18% and 59.05% by weight. Structure refinement was carried out considering

those space groups from I- and P-type tetragonal systems which possess 4 symmetry and

preserve the anion sub-lattice arrangement of the chalcopyrite structure (space group:  $I\bar{4}$  2d)

as well. The results showed that AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method crystallizes

with P-type tetragonal structure (space group:  $P\overline{4}2c$ ; unit-cell parameters a = 6.2443(8) and c

= 12.5058(4) Å), the presence of which was corroborated by selected area electron diffraction

studies.

Key words: AgIn<sub>3</sub>Te<sub>5</sub>, Rietveld refinement, P-type tetragonal, Electron diffraction, PIXE.

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### I. INTRODUCTION

Ag-III-VI<sub>2</sub> based ternary and quaternary chalcopyrite semiconductors have been widely investigated because of their potential application in photovoltaics and nonlinear optics. For example, AgGaTe<sub>2</sub> (band gap 1.16 eV) thin-film based solar cells with efficiency of 4.8% at laboratory scale have been demonstrated (Mandal et al., 2003). Efficiency of 7.3% has been reported (Yamada et al., 2006) for a tandem solar cell with an AgInGaSe<sub>2</sub> absorber layer. AgGaSe<sub>2</sub>, another compound of this family, exhibits a large nonlinear optical coefficient and high transmission in the IR region (Xue et al., 2000). In fact, AgGaSe<sub>2</sub> crystals for second harmonic generation in the IR region are commercially available (http://www.ekspla.com). When the occupancy of cations in the ideal chalcopyrite lattice is disturbed, a series of compounds with general formula  $A^I B_{2n+1}^{III} C_{3n+2}^{VI}$ , where  $n=0,\ 1,\ 2,$  have been reported to stabilize (Zhang et al., 1997). These compounds have been studied with equal interest, ever since the experimental observation of CuIn<sub>3</sub>Se<sub>5</sub> as a segregated phase over CuInSe<sub>2</sub> film surface (Schmid et al., 1993). While a number of Cu based compounds have been investigated, Ag based systems have attracted much less attention. Reported work on Agbased vacancy compounds, mainly concern with Ag-III<sub>5</sub>-VI<sub>8</sub>. The exception being AgIn<sub>3</sub>Te<sub>5</sub>, on which preliminary work was done by O'Kane and Mason (1964) and in fact, its structure has not been resolved yet. Since, the structure of AgInTe<sub>2</sub>  $(I\overline{4}\,2d)$  and AgIn<sub>5</sub>Te<sub>8</sub>  $(P\overline{4}\,2m)$  have been understood fairly well (Diaz et al., 2000; Sanchez et al., 2005), it is of interest to investigate AgIn<sub>3</sub>Te<sub>5</sub>, which is located in between the above two on the Ag<sub>2</sub>Te-In<sub>2</sub>Te<sub>3</sub> tie line in the Ag-In-Te ternary phase diagram (Chiang et al., 1967). The present investigation aims at determining the structure of melt-quenched AgIn<sub>3</sub>Te<sub>5</sub> unambiguously through proton induced X-ray emission (PIXE), X-ray diffraction (XRD) and selected area electron diffraction studies.

The isostructural nature of Cu and Ag based compounds in the I-III-VI<sub>2</sub> family implies that the structure of AgIn<sub>3</sub>Te<sub>5</sub> may be related to that of CuIn<sub>3</sub>VI<sub>5</sub>. Therefore, it is not unreasonable to consider the structures suggested for CuIn<sub>3</sub>VI<sub>5</sub> compounds based on Rietveld and electron diffraction analysis. Thiogallate, stannite and P-type tetragonal structures have been proposed for Cu-In-Se, a widely studied system with compositional ratio close to 1:3:5. Tseng and Wert (1989) have suggested thiogallate structure (space group:  $I\overline{4}$ ) based on electron diffraction data of commercially grown sample with composition CuIn<sub>3</sub>Se<sub>5,33</sub>. A similar conclusion has been arrived at by Bodnar et al. (2006) from an XRD study of single crystal CuIn<sub>3</sub>Se<sub>5</sub>. Hanada et al. (1997) have concluded that CuIn<sub>3</sub>Se<sub>5</sub> crystallizes with stannite structure (space group: I4 2m) based on XRD and electron diffraction analysis of CuIn<sub>3</sub>Se<sub>5</sub> powder obtained from ingots grown by air cooling the melt. Rietveld refinement of crystal structure (Paszkowicz et al., 2004) using XRD data of CuIn<sub>3</sub>Se<sub>5</sub> powder, obtained from single crystal CuIn<sub>3</sub>Se<sub>5</sub>, has led to similar conclusions as well. P-type tetragonal structure with  $P\overline{4}2c$  space group has also been suggested by several authors. The studies include, Rietveld refinement of crystal structures using: i) XRD data of CuIn<sub>3</sub>Se<sub>5</sub> single crystal quenched from 1023 K into water (Honle et al., 1988) and ii) XRD data of CuIn<sub>2</sub>Se<sub>3.5</sub> and CuIn<sub>3</sub>Se<sub>5</sub> powders obtained from furnace cooled ingots (Merino et al., 2000) as well as electron diffraction study of single crystal CuIn<sub>3</sub>Se<sub>5</sub> grown from vertical gradient freeze method (Tham et al., 2000). On the other hand, for the relatively less studied CuIn<sub>3</sub>Te<sub>5</sub>, XRD analysis (Marin *et al.*, 2000) of CuIn<sub>3</sub>Te<sub>5</sub> powder obtained from ingots grown by vertical Bridgman method has yielded a tetragonal chalcopyrite related structure, while Rietveld refinement of crystal structure using XRD data of CuIn<sub>3</sub>Te<sub>5</sub> powder taken from ingots quenched from 1358 to 473 K has yielded P-type tetragonal structure with  $P\overline{4}$  2c space group (Diaz et al., 2005).

It may be understood from the above observations that the structure of CuIn<sub>3</sub>Se<sub>5</sub> and CuIn<sub>3</sub>Te<sub>5</sub> depends on changes in composition as well as on the thermal cycle followed for sample synthesis. It may also be inferred that the structure analysis of I-In<sub>3</sub>-VI<sub>5</sub> compounds, in general, is not straight forward and an exhaustive study is required before any conclusion can be drawn. Accordingly, while refining the structure of AgIn<sub>3</sub>Te<sub>5</sub> we have considered all space groups in I- and P-type tetragonal systems which possess 4 symmetry and also preserve the anion sub-lattice arrangement of the chalcopyrite structure. We have also corroborated the Rietveld refinement results using selected area electron diffraction measurements.

### II. EXPERIMENTAL

# A. Synthesis of bulk AgIn<sub>3</sub>Te<sub>5</sub>

Polycrystalline AgIn $_3$ Te $_5$  was synthesized by melt-quench technique, which involved fusion of constituent elements and subsequent quenching in water. 5N purity Ag, In and Te pieces with compositional ratio 1:3:5 and total mass of about  $\sim 5$  g were taken in a cleaned quartz ampoule, which was then evacuated to a pressure of  $\sim 5\times10^{-6}$  mbar and sealed. The sealed ampoule was heated in a vertical tubular furnace, the temperature of which was controlled to an accuracy of  $\pm 2$  K. The furnace temperature was initially increased to 523 K at a rate of 4 K per min and was maintained at this temperature for 3 h in order to allow the exothermic reaction between In and Te to take place at a controlled rate. Heating was continued at the same rate up to 1273 K, which is higher than the melting points of the constituent elements. The charge in the ampoule was allowed to react in this molten state for 60 h with intermittent shaking in order to improve the homogeneity. Finally, the ampoule with the charge in the molten state was quenched in water. The ingot thus obtained was polycrystalline and was black in color with shiny surface.

# B. Characterization of AgIn<sub>3</sub>Te<sub>5</sub>

#### 1. PIXE Measurement

PIXE measurements were performed using tandem pelletron accelerator facility available at the Centre for Ion Beam Analysis, National University of Singapore, Singapore. The sample for PIXE measurements was in the form of pellet (thickness ~1 mm and diameter 8 mm) made out of AgIn<sub>3</sub>Te<sub>5</sub> powder. The sample was irradiated with collimated proton beam of energy 2 MeV, and the spectra were recorded with a maximum beam current of ~6 nA. The characteristic X-rays emitted from the sample were detected by a liquid N<sub>2</sub> cooled Si(Li) detector having a resolution of 170 eV at 5.9 keV. The detector was kept at an angle of 170° with respect to the incident beam and the characteristic X-rays were collected through a 50-µm thick Mylar window. The spectra were recorded using a Canberra series S-100 multichannel analyzer and were analyzed using the software "GUPIX" (Campbell et al., 2000) in order to determine the elemental concentrations. A digital filter in the software was used to remove the background in the experimental spectra. GUPIX uses a non-linear least square procedure to fit the experimental data and converts the intensities of peaks into concentration of the respective constituent elements. The main experimental parameters which are needed for the analysis are incident ion energy, experimental geometry, detector details, filter details, the instrumental constant H and the collected charge.

### 2. XRD measurement

Powder X-ray diffraction measurements were made at 298 K using a PANalytical (model- X'Pert PRO, equipped with X'Celerator detector) XRD unit with Cu-  $K\alpha$  radiation source in the  $2\theta$  range 10 to 130° with step size of 0.0170 °2 $\theta$  and integration time of ~40s. The X-ray generator was operated at 40 kV and 30 mA and the wavelengths of  $K\alpha_1$  and  $K\alpha_2$  lines were 1.54060 and 1.54443 Å respectively. Theta compensating slit was fixed at 1° and

 $K_{\beta}$  lines present in the diffracted beam were filtered using a nickel filter. Prior to the measurements, the XRD unit was calibrated with silicon (external) standard. Specimen (mortar and pestle ground powder) for XRD measurements was taken in an aluminum well and was gently pressed (without affecting its random orientation) to present a smooth flat surface. Rietveld refinement was carried out using the software *GSAS* (Larson and von Dreele, 2004) supported by *EXPGUI* graphical user interface which allows simultaneous refinement of two wavelengths ( $K_{\alpha l}$  and  $K_{\alpha 2}$  with intensity ratio 0.5, in the present case). Shifted Chebyschev polynomial was used to describe the background and a Pseudo-Voigt profile function was used to model the peak shapes. The quality of fit was described by the discrepancy factors (Young, 1993)  $R_p$ ,  $R_{wp}$ ,  $R_{exp}$ ,  $R_F$ , and  $\chi^2$ , the goodness of fit (*GOF*).

# 3. Electron diffraction measurement

Selected area electron diffraction measurements were made at different zone axis using a Philips CM-12 transmission electron microscope with an accelerating potential of 120 kV and a beam current of a few  $\mu$ A. The diameter of the probing electron beam was about 150 nm. For TEM measurements, fine particles of AgIn<sub>3</sub>Te<sub>5</sub> were collected on carbon coated copper grids from a solution consisting of AgIn<sub>3</sub>Te<sub>5</sub> powder dispersed in acetone/methanol.

### III. RESULTS AND DISCUSSION

# A. PIXE analysis

A Typical 2 MeV PIXE spectrum of bulk  $AgIn_3Te_5$  is shown in Figure 1. The inset to Figure 1 shows, on an expanded scale, the region between 2.7 to 4.3 eV. The characteristic X-ray lines from the constituent elements are marked in the spectrum for convenience. The instrument constant and energy calibration parameters were obtained using a standard sample (quartz) which emitted both K and L X-ray lines in the energy range 2 to 30 keV. Assuming

bulk AgIn<sub>3</sub>Te<sub>5</sub> as a matrix consisting of Ag, In and Te with unknown ratio, a thick target PIXE analysis was carried out. The weights (in percentage) of Ag, In and Te determined from the analysis are 9.76, 31.18 and 59.05 respectively, which show that the synthesized material is near stoichiometric.

# **B.** Rietveld refinement

# 1. Structure refinement based on $I\overline{4}$ , $I\overline{4}$ 2m and $P\overline{4}$ 2c space groups

Powder diffraction data (symbols) of AgIn<sub>3</sub>Te<sub>5</sub> is shown in Figure 2. Rietveld refinement was initiated assuming thiogallate structure with  $I\bar{4}$  space group. In this structure, the atomic position 2a at (0, 0, 0) is shared by both Ag and In atoms whereas the positions 2b at (0, 0, 1/2), 2c at (0, 1/2, 1/4) and 2d at (0, 1/2, 3/4) are occupied by In atoms. Te atoms occupy the site 8g at (x, y, z), where x, y and z are free parameters. The assigned occupancies were (0.8Ag + 0.2In) at 2a, 1 at 2b, 1 at 2c, 0.2 at 2d and 1 at 8g. It is to be noted here that all Rietveld refinements have been carried out assuming the ideal compositional ratio (1:3:5) as the composition of AgIn<sub>3</sub>Te<sub>5</sub> is found to be near stoichiometric. The refinement converged satisfactorily to  $R_{wp} = 7.53$  % (GOF: 2.031). The calculated pattern, however exhibited an additional reflection 002, the structure factor of which is  $1.6f_{Ag}$ , where  $f_{Ag}$  is Ag atomic scattering factor. Since the 002 reflection was not observed in the experimental pattern, refinement was performed with redistributed In occupancy (0.1 at 2a and 0.3 at 2d) that reduces the 002 reflection structure factor to  $1.6f_{Ag} - 0.4f_{In}$ , where,  $f_{In}$  is the atomic scattering factor for In. The refinement converged with a marginal reduction in  $R_{wp}$  value (7.38%, GOF: 1.954), but the anion positional parameters had to be kept fixed during the refinement.

Refinement was continued assuming stannite structure with  $I\overline{4}\,2m$  space group. In the unit cell, Ag atoms occupy 2a at (0, 0, 0), In atoms occupy 2b at (0, 0, 1/2) and 4d at (0, 1/2, 1/2)

1/4), while Te atoms occupy 8i at (x, x, z). The assigned site occupancies were 0.8 at 2a, 0.4 at 2b, 1 at 4d and 1 at 8i. The refinement converged to  $R_{wp} = 6.38$  % (GOF: 1.463), which is lower than that obtained for the refinement done assuming  $I\bar{4}$  space group. However, the calculated pattern showed a low-intensity additional reflection 002, similar to the previous refinement. In order to verify if reduction in the intensity of 002 reflection would improve  $R_{wp}$ , refinement was performed by reducing the structure factor from  $1.6f_{Ag} - 3.2f_{In}$  to  $1.6f_{Ag} - 2.6f_{In}$  by redistributing In occupancy (0.55 at 2b, 0.925 at 4d) and leaving Ag and Te occupancies and composition unaltered. However, the refinement converged to higher value of  $R_{wp}$  (6.62 %, GOF: 1.575), suggesting that the quality of refinement decreases.

Refinement was continued further assuming P-type tetragonal structure with  $P\bar{4}$  2c space group. In the unit cell, Ag atoms occupy 2e at (0, 0, 0), In atoms occupy 2b at (1/2, 0, 1/4), 2d at (0, 1/2, 1/4) and 2f at (1/2, 1/2, 0), and Te atoms occupy 8n at (x, y, z). Vacancies are assumed to be present at the Ag site (2e) and the In site (2b). The refinement converged satisfactorily with  $R_{wp} = 6.09\%$  (GOF: 1.328) which is the lowest among the  $R_{wp}$  values obtained so far. The optimized occupancies are 0.8 at 2e, 0.4 at 2b, 1 at 2f, 1 at 2d and 1 at 8n. The results are presented in Figure 2 along with the experimental pattern. Unlike in the previous two cases, the calculated pattern did not contain any additional peak. Further, all peaks observed in the experimental XRD pattern were found to obey the general reflection conditions for the space group  $P\bar{4}$  2c given in the International Tables of X-ray Crystallography (Henry and Lonsdale, 1965). The unit-cell parameters obtained are a = 6.2443(8) and c = 12.5058(4) Å, with a tetragonal distortion (q = c/2a) ~1.001. The refined structural parameters are given in Table I.

The experimental and calculated powder diffraction data for bulk AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method is listed in Table II. For the sake of brevity, only the reflections with relative intensity more than 0.3% are considered while forming Table II. The reflection with the highest intensity, 112, is observed at  $2\theta = 24.556^{\circ}$  and is mainly due to anion sub-lattice as in AgInTe<sub>2</sub>. Reflections such as 202, 114, 212, 214, 306, 334 and 426 are not allowed as per the general reflection conditions for chalcopyrite structure. They are unique to offstoichiometric or defect chalcopyrite structure. Reflections with extinction condition h+k+l=12n+1 are characteristic of P-type tetragonal class while those with extinction condition h+k+1= 2n are allowed for both P-type and I-type tetragonal systems. Specifically, reflections which obey the conditions, l = 4n (with odd h, k-indices) or l = 4n+2 (with even, h, k-indices) are expected for defect I-type structure. For P-type defect structure, reflections with condition l = 4n+2 (with odd/even h, k-indices) are expected in addition. Thus, for instance 212, the highest intensity reflection among these additional ones is expected for  $P\overline{4}\,2c$  alone. The above observations clearly favor  $P\overline{4}$  2c space group over  $I\overline{4}$  and  $I\overline{4}$  2m space groups. However, choice of  $P\overline{4}2c$  space group without further consideration is not possible at this stage since the experimental powder XRD data did not contain all reflections expected for  $P\overline{4}2c$  space group. The 002 reflection for instance, although allowed in  $P\overline{4}2c$  space group was absent in the experimental XRD pattern. The reason for this may be that either these characteristic reflections are too weak to contribute or the structure itself is different. In order to eliminate the latter possibility, it is essential to consider the space groups in P-type and Itype tetragonal systems with  $\frac{1}{4}$  symmetry, in general.

# 2. Discussion on other space groups in P- and I-type tetragonal systems with $\frac{1}{4}$ symmetry

The remaining space groups with  $\bar{4}$  symmetry in the P-type tetragonal system are  $P\bar{4}$ ,  $P\bar{4}\,2m$ ,  $P\bar{4}\,2l$ ,  $P\bar{4}\,2$ 

Structure refinement performed assuming  $P\overline{4}$  space group with Ag on 1a at (0, 0, 0) and on 1b at (0, 0, 1/2), In on 1c at (1/2, 1/2, 0), 1d at (1/2, 1/2, 1/2), 2g at (0, 1/2, 1/4) and 2g at (0, 1/2, 3/4), and Te on 4h at (x, y, z) and 4h at (x, y, z+1/2) was found to converge only with fixed anion positional parameters. The minimum  $R_{wp}$  obtained was 7.92% (GOF: 2.249, site occupancy factors: 0.9 at 1a, 0.7 at 1b, 0.4 at 1c and 1d, 1 at 2g and 1 at 4h). In  $P\overline{4}$  2m space group, Ag occupies 1a and 1c respectively at (0, 0, 0) and (0, 0, 1/2), In occupies 1b at (1/2, 1/2, 1/2), 1d at (1/2, 1/2, 0) and 4m at (0, 1/2, 1/4), and Te occupies 4n at (x, x, z) and 4n at (x, x, z+1/2). The minimum possible  $R_{wp}$  obtained from structure refinement was 8.21% (GOF: 2.420, site occupancy factors: 0.6 at 1a, 1 at 1c, 0.23 at 1b, 0.85 at 1d, 0.93 at 4m and 1at 4n). In  $P\overline{4}$  2<sub>1</sub>m space group, the atomic positions in the unit cell are Ag on 2a at (0, 0, 0), In on 2b at (0, 0, 1/2), 2c at (0, 1/2, 1/4) and 2c at (0, 1/2, 3/4), and Te on 4e at (x, 1/2+x, z)

and 4e at (x, 1/2+x, z+1/2). The refinement converged to  $R_{wp} = 7.65\%$  (GOF: 2.098, site occupancy factors: 0.8 at 2a, 1 at 2b, 0.4 for z = 1/4 and 1 for z = 3/4 at 2c, and 1 at 4e).

In all the above refinements the calculated patterns exhibited low-intensity hhl reflections 002, 003/111 and 113, regardless of Ag and In site occupancies. In addition, the refinements based on these space groups yielded higher  $R_{wp}$  values compared to that obtained for  $P\bar{4}2c$  space group. Finally, structure refinement assuming  $P\bar{4}2_1c$  space group was carried out with Ag on 2a at (0, 0, 0), In on 2b at (0, 0, 1/2) and 4d at (0, 1/2, 1/4), and Te on 8e at (x, y, z). The refinement converged only with fixed anion positional parameters and the minimum  $R_{wp}$  obtained was 8.94% (GOF: 2.868, site occupancy factors: 0.8 at 2a, 0.5 at 2b, 0.95 at 4d and 1 at 8e), which is higher than that obtained for  $P\bar{4}2c$ . Further, the calculated pattern was always found to contain a 002 peak with finite intensity, regardless of the occupancies at In sites.

### 3. Discussion on hhl reflections

In all refinements except that based on  $P\bar{4}\,2c$  space group, the 002 reflection with observable intensity was present in the calculated pattern. In the refinements with  $P\bar{4}$ ,  $P\bar{4}\,2m$  and  $P\bar{4}\,2_1m$  space groups, 003/111 and 113 reflections appeared in the calculated pattern, in addition. The 002 reflection is characteristic of defect phases (extinction condition l=4n+2 with even h, k indices) and is allowed in the space groups  $P\bar{4}\,2c$  and  $I\bar{4}\,2m$  under the general reflection condition hhl: l=2n, while in  $I\bar{4}$  space group it is allowed under the condition h+k+l=2n. The reflections 003/111 and 113 are allowed in addition to 002 in  $P\bar{4}$ ,  $P\bar{4}\,2m$  and  $P\bar{4}\,2m$  space groups under the condition hhl: l=0dd or even. In order to verify if the intensities of these reflections are really negligible in the experimental data, high-resolution

scans (step size: 0.002° and acquisition time 60 s) were taken. Figures 3(a) and 3(b) are examples of high-resolution scans taken around 14° and 21° respectively. The large circles in Figures 3(a) and 3(b) indicate the regions where the 002 and 003/111 reflections are expected. Absence of any feature indicates that these reflections, if present, have negligibly small relative intensities. The reason for the absence of the 002 reflection may be that its structure factor in  $P\overline{4}2c$  space group (1.6f<sub>Ag</sub> - 0.8f<sub>In</sub>) has the least value among the structure factors in the space groups considered and therefore its intensity can be annulled easily, while maintaining stoichiometry. The absence of 003/111 reflections in addition to 002, indicates that the space group  $P\overline{4}$  or  $P\overline{4}$  2m or  $P\overline{4}$  21m is not suitable. Figure 3(c) shows powder diffraction data around the region in which the 114 peak appears. Deconvolution of the data clearly reveals the nearby 212 reflection, which is disallowed for the I-type tetragonal system. Although the 212 peak is close to the 114 peak, it could be resolved well in electron diffraction patterns, a discussion of which will appear in the latter sections. Thus, it may be concluded from the Rietveld analysis that among all space groups considered,  $P\overline{4}\,2c$  is the most likely space group for near stoichiometric AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench technique.

# 4. Structure of AgIn<sub>3</sub>Te<sub>5</sub>

The choice of  $P\overline{4}\,2c$  space group ensures that the anion sub-lattice remains undisturbed as that in chalcopyrite structure. The cationic sub-lattice is occupied by Ag and In atoms, and vacancies at four different Wyckoff positions (Table I) with no evidence of mixed occupancies of cations. The vacancies may be distributed statistically or arranged in a particular order. Further, the rearrangement of Ag and In atoms and the introduction of vacancies in cationic sub-lattice lead to the displacement of Te atoms (with three degrees of freedom) from their ideal position 1/4, 1/4, 1/8. Moreover, the refined Ag-Te bond length

(2.72 Å) in AgIn<sub>3</sub>Te<sub>5</sub> unit cell was found to be smaller compared to that (2.76 Å) in AgInTe<sub>2</sub> (Xue *et al.*, 2000) which may be attributed to the presence of Ag vacancies. Similar observations were made on CuIn<sub>3</sub>Te<sub>5</sub> and CuIn<sub>3</sub>Se<sub>5</sub> compounds by Rincon *et al.* (2000) and Paszkowicz *et al.*, (2004) respectively. Furthermore, the different bond lengths obtained between In and Te atoms can be explained on the basis of displacement and electronegativity of Te atoms, and the occupancies of In atoms.

Figure 4 shows the unit cell of  $AgIn_3Te_5$ , which was constructed with the refined structural parameters as guide. When the site occupancies are normalized to Te atom occupancy, the chemical formula of the compound can be written as  $Ag_{0.8}In_{2.4}Te_4$  with two formula units in a single unit cell. The dotted lines represent the unit-cell boundary while the bonding between the atoms is shown by thick solid lines. It can be seen from Figure 4 that the unit cell has five different types of tetrahedral structures viz., ( $\Box + Ag$ )-Te<sub>4</sub>, ( $\Box + In1$ )-Te<sub>4</sub>, In2-Te<sub>4</sub>, In3-Te<sub>4</sub> and ( $\Box + AgIn_3$ )-Te, where  $\Box$  denotes vacancy. The bond angles in the tetrahedra varied from 103.76° to 116.77°. However, the average bond angle in each of the tetrahedron was found to be close to the ideal value of 109.47°.

# C. Electron diffraction analysis

Selected area electron diffraction patterns of  $AgIn_3Te_5$  particles recorded along two different zone axes are shown in Figures 5(a) and (b). The zone axis for the pattern shown in Figure 5(a) is  $[\overline{3}31]$  and that for the pattern shown in Figure 5(b) is  $[22\overline{1}]$ . A well-ordered array of spots observed in the patterns indicates the crystalline quality of the particle under investigation. The patterns were indexed following the usual procedure. The pattern indexed with the zone axis  $[\overline{3}31]$  (Figure 5(a)) shows 103, 12 $\overline{3}$ , 220 and 323 reflections while that indexed with the zone axis  $[22\overline{1}]$  (Figure 5(b)) exhibits  $\overline{2}$  20, 204, 024, 102 and  $\overline{1}$  22

reflections. The spots corresponding to the reflections 102 and 122 are weak in intensity (Figure 5(b)) when compared to the others and may be attributed to their small structure factors. The observed reflections may be categorized as follows. The reflections 220,  $\overline{2}$  20, 204 and 024 are typical of zinc blende lattice (extinction condition h+k+l=2n and even l-1indices). The reflections 103,  $12\overline{3}$ , and 323 are specifically from chalcopyrite lattice (h+k+l)= 2n and odd l- indices). The reflections 102 and  $\bar{1}$ 22 are unique to P-type tetragonal structure with  $P\bar{4}2c$  space group. Thus, while the zone axis  $[\bar{3}31]$  limits the observable reflections (Figure 5(a)) to some of those from zinc blende and chalcopyrite lattices, the zone axis [221] allows some of the reflections which are unique to P-type tetragonal structure to be observed as well. The presence of 1 22 reflection (denoted 212 in the XRD pattern) corroborates well the conclusions drawn from Rietveld analysis on the existence of  $P\overline{4}$  2c. It is worth to note here that while the 122 reflection could be identified uniquely through selected area electron diffraction pattern, it was close to 114 reflection in the XRD pattern. The angular separation between 114 and 212 reflections in XRD pattern is determined by the tetragonal distortion. In the absence of tetragonal distortion they will be degenerate, but can still be resolved in electron diffraction pattern. Thus, from the combined analysis of PIXE, XRD and electron diffraction we can safely conclude that melt-quenched AgIn<sub>3</sub>Te<sub>5</sub> with near stoichiometric composition crystallizes with  $P\overline{4}\,2c$  space group.

### IV CONCLUSION

  $I\overline{4}$  and  $I\overline{4}$  2m, which preserve the anion sub-lattice arrangement of the chalcopyrite unit cell. The results have shown that near stoichiometric AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method crystalizes with P-type tetragonal structure (space group:  $P\overline{4}$  2c), the existence of which has also been confirmed by selected area electron diffraction patterns.

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# Figure and Table captions

- **Figure 1.** Typical PIXE spectrum of bulk AgIn<sub>3</sub>Te<sub>5</sub>. The circles represent experimental data and the continuous line denotes the calculated curve. The inset shows the spectrum in the range 2.7 to 4.25 keV, on an expanded scale.
- **Figure 2.** Experimental XRD pattern and the results of Rietveld refinement for AgIn<sub>3</sub>Te<sub>5</sub>. The inset shows the data in the range 85° to 130°, on an expanded scale. The crosses and the overlying solid line represent the experimental data and the calculated profile respectively. The short vertical markers indicate possible Bragg reflections whereas the bottom curve denotes the difference between the experimental and calculated data.
- Figure 3. High resolution (step size: 0.002°, acquisition time 60 s) XRD data of AgIn<sub>3</sub>Te<sub>5</sub> recorded in different 2θ ranges. The large circle in panel (a) marks the region where 002 reflection is expected, while that in panel (b) depicts the region where 003 reflection is expected. The presence of two closely spaced reflections (114 and 212) can be seen clearly in panel (c). In panel (c), the grey lines show the individual deconvolutions while the dark line shows the overall sum.
- **Figure 4.** Unit cell of AgIn<sub>3</sub>Te<sub>5</sub> constructed using refined cell parameters as guide. Site occupancy factors of Ag, In1, In2, In3 and Te atoms are 0.8, 0.4, 1, 1 and 1 respectively. The dotted lines denote the cell boundary.
- **Figure 5.** Electron diffraction patterns recorded on fine AgIn<sub>3</sub>Te<sub>5</sub> particles. The zone axes are (a)  $\lceil \overline{3}31 \rceil$  and (b)  $\lceil 22\overline{1} \rceil$ .
- **Table I.** Refined structure parameters for AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method. Structure: P-type tetragonal, space group:  $P\overline{4}$  2c, lattice parameters: a = 6.2443(8) and c = 12.5058(4) Å, unit cell formula weight = 1744.525 and density = 5.491 gm/cm<sup>3</sup>. The discrepancy factors are:  $R_p = 4.75\%$ ,  $R_{wp} = 6.09\%$ ,  $R_{exp} = 5.28\%$  and  $R_F^2 = 7.22\%$ . The Goodness of fit,  $\chi^2 = 1.328$ .
- **Table II.** Powder XRD data for AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method. The space group is  $P\bar{4}$  2c. Reflections with relative peak heights < 0.3% in the experimental data are not included in the table. Values of  $2\theta_{\rm obs}$ ,  $d_{\rm obs}$  and  $I_{\rm obs}$  are obtained from the experimental data using the software X'pert HighScore Plus, while values of  $2\theta_{\rm cal}$ ,  $d_{\rm cal}$  and  $I_{\rm cal}$  are calculated from refined unit-cell parameters and Miller indices (hkl).

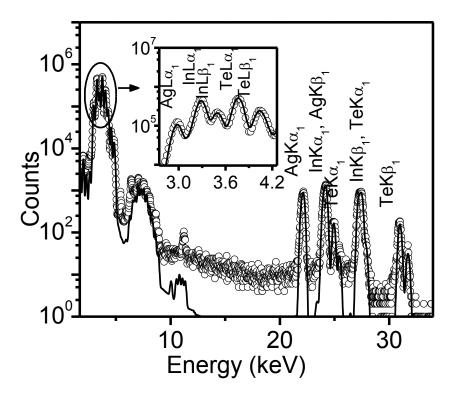


Figure 1

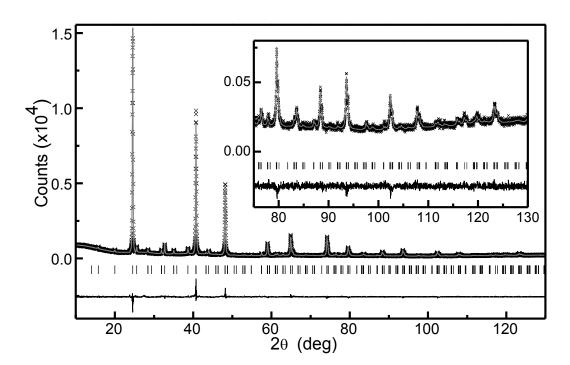


Figure 2

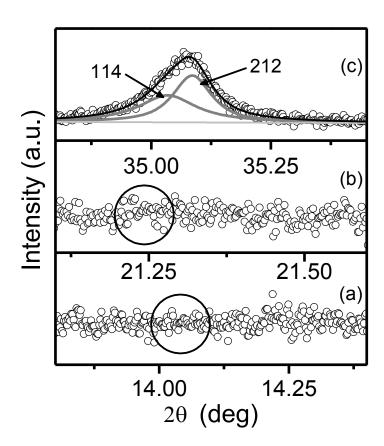


Figure 3

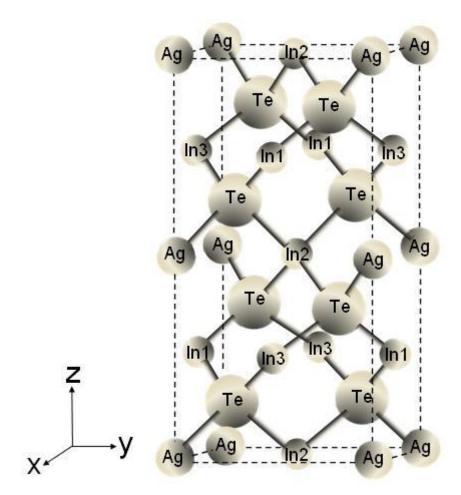
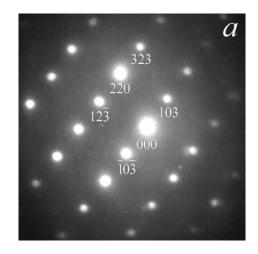


Figure 4



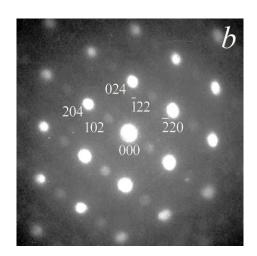


Figure 5

Table I. Refined structure parameters for AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method. Structure: P-type tetragonal, space group:  $P \ \bar{4} \ 2c$ , unit-cell parameters: a = 6.2443(8) and c = 12.5058(4) Å, unit-cell formula weight = 1744.525 and density = 5.491 gm/cm<sup>3</sup>. The discrepancy factors are:  $R_p = 4.75\%$ ,  $R_{wp} = 6.09\%$ ,  $R_{exp} = 5.28\%$  and  $R_F^2 = 7.22\%$ . The goodness of fit,  $\chi^2 = 1.328$ .

Atom	Wyckoff position	Atomic position (x,y,z)	Occupancy	Isotropic thermal parameter (Uiso) Å <sup>2</sup>	
Ag	2e	0, 0, 0	0.8	0.02048	
In1	2b	1/2, 0, 1/4	0.4	0.05239	
In2	2f	1/2, 1/2, 0	1	0.02762	
In3	2d	0, 1/2, 1/4	1	0.02895	
Te	8n	0.261, 0.225, 0.133	1	0.03059	
	Bond le	ngth ( Å)	Bor	parameter (Uiso) 2 0.02048 0.05239 0.02762 0.02895 0.03059 and angle (°) e 112.035( 104.456( 2 111.715( 3 112.889( 3 104.151( e 112.031( 109.132( 107.287(	
A	g-Te	2.72434(4)	Te-Ag- Te	e 112.035(1)	
				104.456(2)	
In	1-Te	2.51435(3)	In1-Te-In	2 111.715(1)	
In	2-Te	2.82017(4)	In1-Te-In	3 112.889(2)	
In	3-Te	2.78105(3)	In2-Te-In	3 104.151(	
			Te-In1-Te	e 112.031(1)	
				109.132(1)	
				107.287(1)	
			Te-In2-Te	110 404/1	

107.444(2)

116.776(2) 108.155(1) 103.763(1)

114.948(1)

105.553(2)

106.747(1)

Te-In3-Te

Ag-Te-In1

Ag-Te-In2

Ag-Te-In3

Table II. Powder XRD data for AgIn<sub>3</sub>Te<sub>5</sub> synthesized by melt-quench method. The space group is  $P\bar{4}$  2c. Reflections with relative peak heights < 0.3% in the experimental data are not included in the table. Values of  $2\theta_{\rm obs}$ ,  $d_{\rm obs}$  and  $I_{\rm obs}$  are obtained from the experimental data using the software X'pert HighScore Plus, while values of  $2\theta_{\rm cal}$ ,  $d_{\rm cal}$  and  $I_{\rm cal}$  are calculated from refined unit-cell parameters and Miller indices (hkl).

_								
	2 θ <sub>obs</sub> (°)	$d_{ m obs}({ m \AA})$	$I_{ m obs}(\%)$	(hkl)	2 θ <sub>cal</sub> (°)	$d_{\mathrm{cal}}(\mathring{\mathrm{A}})$	<i>I</i> <sub>cal</sub> (%)	Δ2 <i>θ</i> (°)
	15.735	5.6273	0.76	101	15.744	5.5866	0.64	-0.009
	19.970	4.4426	0.97	110	19.987	4.4154	0.43	-0.017
	24.541	3.6245	100.00	112	24.556	3.6068	100.00	-0.015
	25.549	3.4837	2.43	103	25.567	3.4670	2.95	-0.018
	28.360	3.1445	1.15	004	28.419	3.1265	0.62	-0.059
	28.464	3.1333	1.67	200	28.459	3.1222	0.94	0.005
	31.898	2.8033	1.98	202	31.907	2.7933	1.67	-0.009
	32.709	2.7357	4.47	2 1 1	32.727	2.7254	5.09	-0.018
	34.967	2.5640	1.34	1 1 4	35.034	2.5516	1.42	-0.067
	35.074	2.5564	2.06	2 1 2	35.059	2.5498	0.48	0.015
	38.628	2.3290	2.97	105	38.643	2.3218	1.14	-0.015
	38.669	2.3266	2.67	2 1 3	38.674	2.3201	1.70	-0.005
	40.623	2.2191	43.89	204	40.704	2.2092	51.27	-0.081
	40.717	2.2142	72.24	220	40.733	2.2077	25.01	-0.016
	43.972	2.0576	2.16	3 0 1	43.961	2.0532	1.62	0.011
	48.033	1.8926	12.46	116	48.135	1.8849	14.75	-0.102
	48.164	1.8878	39.39	3 1 2	48.186	1.8830	28.20	-0.023
	48.774	1.8656	1.08	2 1 5	48.734	1.8631	0.49	0.040
	54.916	1.6706	0.30	3 1 4	54.844	1.6695	0.47	0.072
	57.465	1.6024	1.26	3 2 3	57.475	1.5993	1.90	-0.011
	58.963	1.5652	6.36	008	58.935	1.5632	3.24	0.027
	59.011	1.5641	7.00	400	59.024	1.5611	6.07	-0.013
	61.008	1.5175	0.70	226	60.985	1.5156	0.57	0.023
	61.506	1.5064	1.23	2 1 7	61.464	1.5049	0.53	0.042
	61.544	1.5056	0.96	4 1 1	61.530	1.5035	0.62	0.014
	62.949	1.4753	0.67	118	62.921	1.4736	0.67	0.028
	64.903	1.4356	11.30	3 1 6	64.898	1.4335	9.49	0.005
	64.987	1.4339	5.34	3 3 2	64.941	1.4326	4.69	0.046
	65.403	1.4258	2.54	3 2 5	65.393	1.4238	1.45	0.010
	65.416	1.4255	2.49	4 1 3	65.414	1.4234	1.21	0.002
	72.816	1.2978	0.37	4 1 5	72.857	1.2955	0.84	-0.041
	74.147	1.2778	8.58	228	74.172	1.2758	5.11	-0.025

74.212	1.2768	11.39	424	74.231	1.2749	10.05	-0.019
76.441	1.2450	1.00	4 3 1	76.502	1.2427	0.87	-0.061
77.799	1.2267	0.43	3 1 8	77.765	1.2257	0.68	0.034
79.560	1.2039	4.04	1 1 10	79.499	1.2033	2.00	0.061
79.570	1.2038	3.97	3 3 6	79.577	1.2023	1.82	-0.007
79.594	1.2035	3.55	5 1 2	79.616	1.2018	3.63	-0.022
83.119	1.1612	0.51	2 0 10	83.027	1.1609	0.55	0.092
83.429	1.1576	0.64	417	83.527	1.1552	0.48	-0.099
83.581	1.1559	1.18	5 2 1	83.585	1.1546	0.90	-0.004
88.341	1.1055	2.43	408	88.317	1.1046	2.72	0.024
88.366	1.1052	2.31	440	88.394	1.1039	1.32	-0.028
88.468	1.1042	1.76	3 1 10	88.507	1.0565	2.05	-0.039
93.560	1.0570	2.59	5 1 6	93.584	1.0559	1.99	-0.024
93.598	1.0567	2.66	5 3 2	93.622	1.0555	1.95	-0.024
101.136	0.9973	0.45	613	101.095	0.9968	0.60	0.041
102.246	0.9895	1.11	2 0 12	102.266	0.9885	1.69	-0.020
102.365	0.9886	1.94	604	102.423	0.9875	1.44	-0.058
102.520	0.9876	1.01	620	102.443	0.9873	1.38	0.077
107.801	0.9534	1.41	3 3 10	107.741	0.9530	0.89	0.060
107.843	0.9531	1.14	5 3 6	107.821	0.9525	1.71	0.022
115.824	0.9092	0.45	5 4 5	115.830	0.9086	0.44	-0.006
117.226	0.9023	0.63	448	117.241	0.9017	1.30	-0.015
119.679	0.8909	0.45	529	119.700	0.8903	0.51	-0.021
119.856	0.8901	0.71	617	119.744	0.8901	0.41	0.112
123.114	0.8761	1.00	1 1 14	123.118	0.8755	0.59	-0.004
123.290	0.8753	1.29	5 1 10	123.256	0.8750	1.21	0.034
123.420	0.8748	0.97	7 1 2	123.394	0.8744	1.07	0.026